

V20

Features

- Switch & Attenuator Die
- Extensive Selection of I-Region Lengths
- Hermetic
- Glass Passivated CERMACHIP[®]
- Oxide Passivated Planar Chips
- Voltage Ratings to 3000V
- Fast Switching Speed
- Low Loss
- High Isolation
- RoHS Compliant

Description

M/A-COM Technology Solutions offers a comprehensive line of low capacitance, planar and mesa, silicon PIN diode chips which use ceramic glass and silicon nitride passivation technology. The Silicon PIN Chip series of devices cover a broad spectrum of performance requirements for control circuit applications. They are available in several choices of I-region lengths and have been optimally designed to minimize parametric trade offs when considering low capacitance, low series resistance, and high breakdown voltages. Their small size and low parasitics, make them an ideal choice for broadband, high frequency, micro-strip hybrid assemblies.

The attenuator line of PIN diode chips are a planar or mesa construction and because of their thicker I-regions and predictable $R_{\rm s}$ vs. I characteristics, they are well suited for low distortion attenuator and switch circuits. Incorporated in the chip's construction is M/A-COM Tech's, time proven, hard glass, CERMACHIP[®]. The hard glass passivation completely encapsulates the entire PIN junction area resulting in a hermetically sealed chip which has been qualified in many military applications. These CERMACHIP[®] diodes are available in a wide range of voltages, up to 3,000 volts, which are capable of controlling kilowatts of RF power.

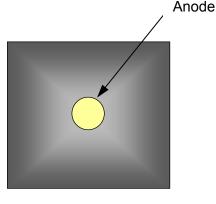
Many of M/A-COM Tech's silicon PIN diode chips are also available in several different package styles. Please refer to the "Packaged PIN Diode Datasheet" for case style availability and electrical specifications located on the M/A-COM Tech website at :

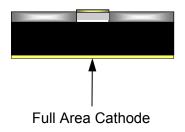
macomtech.com/datasheets/packagedpindiodes

and for high voltage, high power devices at :

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macomtech.com/datasheets/MA4PK2000_3000_Series





Absolute Maximum Ratings¹ T_{AMB} = +25°C (Unless otherwise specified)

Parameter	Absolute Maximum
Forward Current (I _F)	Per P/N R _s vs. I Graph
Reverse Voltage (V _R)	Per Specification Table
Power Dissipation (W)	175°C – T _{ambient} °C Theta
Operating Temperature	-55°C to +175°C
Storage Temperature	-55°C to +200°C
Junction Temperature	+175°C
Mounting Temperature	+320°C for 10 seconds

1. Exceeding these limits may cause permanent damage to the chip

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Low Capacitance PIN Specification @ T_{AMB} = +25°C

				Nominal Characteristics						
Part Number	Max. Rev. Voltage ³ V _{R <10 µA} V _{DC}	Max. Cap. 1 MHz C _{j @ -10 V} pF	Max. Series Res. 500 MHz R _{S @ 10 mA} Ω	Carrier Lifetime ¹ Τ _L ηS	Reverse Recovery Time ² T _{RR} ηS	l Region Length μm	Theta °C/W	Anode Diameter ± 0.5 mils	Chip Size ± 0.5 mils	Chip Thk. ± 0.5 mils
MA4P161-134	100	0.10	1.50	150	15	13	65	3.5	13X13	6
MA4P203-134	100	0.15	1.50	150	25	13	75	3.1	13X13	6
MA4P7493-134	150	0.05	1.80	80	8	19	60	3.8	13X13	6.5
MADP-000165-01340W	200	0.06	2.50	200	20	19	30	1.8	13X13	7
MADP-000135-01340W	200	0.15	1.20	440	44	19	30	3.1	13x13	10

Notes:

1. Nominal carrier life time (T_L) specified at I_F = + 10mA , I_{REV} = - 6mA.

2. Nominal reverse recovery time specified at I_{F} = + 20mA , I_{REV} = - 200mA.

3. Reverse Voltage (V_R) is sourced and the resultant reverse leakage current (I_R) is measured to be <10 μ A.

Attenuator PIN Specification @ T_{AMB} = +25°C

					Nominal Characteristics						
Part Number	Max. Rev. Voltage ² V _{R <10 µA} V _{DC}	Max. Cap. 1MHz C _{j @ -100 V} pF		Lifetime ¹	Series Res. 100MHz R _{S @ 10 μA} Ω	Series Res. 100MHz R _{S@1mA} Ω	l Region Length mils	Theta °C/W	Anode Diameter ± 0.5 mils	Chip Size ± 2 mils	Chip Thk. ±1 mils
MA47416-132	200	0.15	6	2	2000	30	4	30	7.5 X7.5 ³	19X19	7
MA47418-134	200	0.15	3	1	500	15	2	25	7.5	13X13	7

Notes:

- 1. Nominal carrier life time (T_L) specified at I_F = + 10mA, I_{REV} = 6mA.
- 2. Reverse Voltage (V_R) is sourced and the resultant reverse leakage current (I_R) is measured to be <10 μ A.
- 3. Anode top contact is square.

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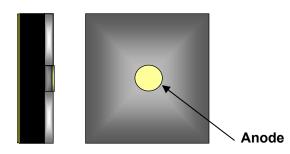
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CERMACHIP[®] PIN Chips Specification @ T_{AMB} = +25°C

		Unless otherwise noted	Unless otherwise noted	Nominal Characteristics					
Part Number	Max. Rev. Volt. ⁵ V _{R < 10 μA} V _{DC}	Max. Cap. 1 MHz CJ _{@ -100 V} pF	Max. Series Res. 100 MHz R _{S @ 100 mA} Ω	Carrier Lifetime ⁴ µS	l Region Length μm	Theta °C/W	Anode Dia. ± 0.5 mils	Chip size ± 2.0 mils	Chip Thk. ± 1.0 mils
MA4P303-134	200	0.15 @ 10 V	1.5 @ 10 mA ²	0.3	20	30	3.0	13X13	10.0
MA4P404-132	250	0.20 @ 50 V	0.70 @ 50 mA ²	0.6	30	20	6.8	20X20	10.0
MA4P504-132	500	0.20	0.60	1	50	20	6.8	20X20	10.0
MA4P505-131	500	0.35	0.45	2	50	14	13.0	27X27	11.0
MA4P506-131	500	0.70	0.30	3	50	11	15.8	27X27	12.0
MADP-000488-13740W	900	0.16 @ 50V	1.6 @ 50 mA	4	140	45	12.2	23X23	13.5
MA4P604-131	1000	0.30	1.00	3	90	10	17.0	27X27	13.5
MA4P606-131	1000	0.60	0.70	4	90	8	21.0	32X32	14.0
MA4P607-212	1000	1.30	0.40	12	127	4	37.0	62X62	18.5
MA4PK2000-223 ¹	2000	2.40	0.20 @ 500 mA ³	30	230	2	72.0	111X111	21.0
MA4PK3000-1252 ¹	3000	2.90	0.25 @ 500 mA ³	60	350	1.5	85.0	172X172	28.0

Notes:

- 2. Test Frequency = 500 MHz
- 3. Test Frequency = 4 MHz
- 4. Nominal carrier lifetime (T_L) specified at I_F = +10 mA , I_{REV} = 6 mA.
- 5. Minimum specified V_R (Reverse Voltage) is sourced and the resultant reverse leakage current (I_{REV}) is measured to be <10 μ A.



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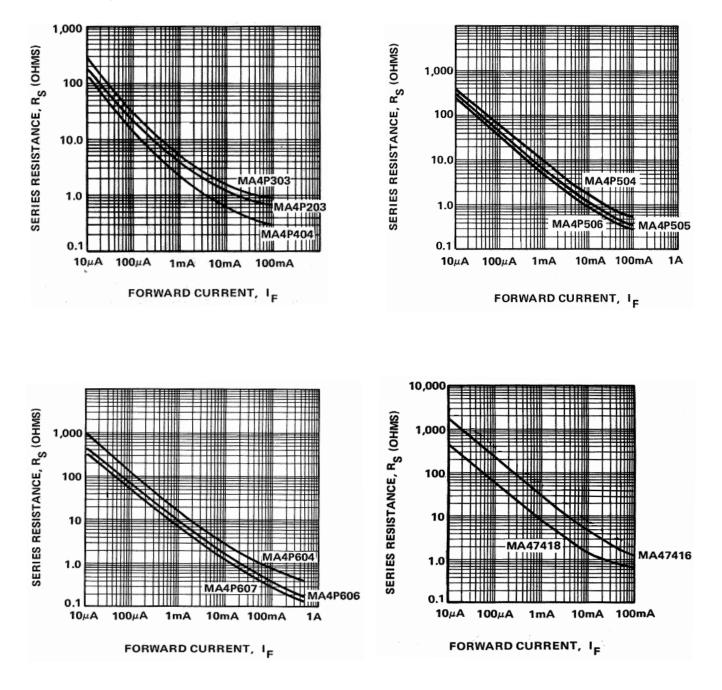
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^{1.} Upon completion of circuit installation, the chip must be covered with a dielectric conformal coating such as SYLGARD 539[®] to prevent voltage arcing.



V20



Typical Series Resistance vs. Forward Current Performance

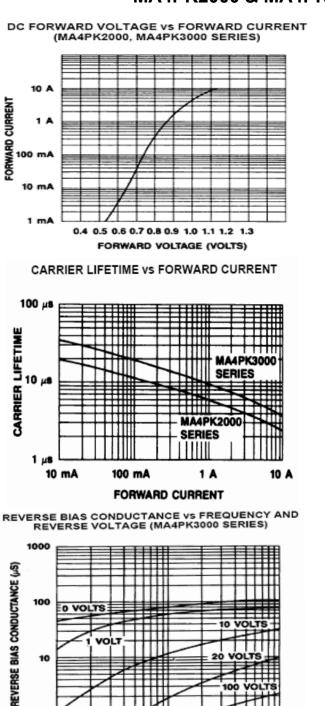
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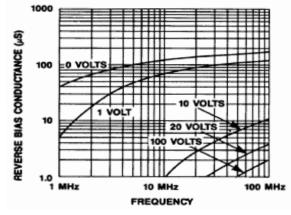


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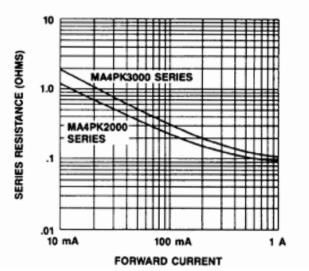


MA4PK2000 & MA4PK3000 (2kV & 3kV) Chips

REVERSE BIAS CONDUCTANCE vs FREQUENCY AND REVERSE VOLTAGE (MA4PK2000 SERIES)



SERIES RESISTANCE vs CURRENT FREQUENCY AT 100 MHz



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10 MHz

FREQUENCY

100

100 MHz

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10

1.0 1 MHz

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Package Availability Table

Base Part Number	Available ODS Package Styles
MA4P161	None. Use MA4P203 as alternative
MADP-000165	None
MADP-000135	None
MA47416	None
MA47418	None
MA4P203	30, 32, 94, 111, 1056
MA4P303	32, 36, 94, 120, 186, 255, 1088
MA4P404	30, 31, 36, 111, 258,1072T*
MA4P504	30, 120, 144, 186, 255,1072T*
MA4P505	36, 255, 1072T*
MA4P506	30, 31, 36, 255, 258, 1072T*
MA4P604	30, 43, 255, 258
MA4P606	30, 36, 258
MA4P607	43, 296
MA4P709	150
MA4P7493	None
MA4PK2000	1027, 1048,1082,
MA4PK3000	1073,1074,1084,

*Note: "T" after the package style number indicates tape and reel.

1072T = 1500pcs/reel

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Datasheets for electrical specifications of packaged devices can be found at :

macomtech.com/datasheets/packagedpindiodes

and for high voltage, high power devices

macomtech.com/datasheets/MA4PK2000 3000 Series

For package outlines refer to web page: macomtech.com/Content/outlinedrawings

Package Parasitic Capacitance

Package Style	Cap. (pF)
30	0.18
31	0.18
32	0.30
36	0.18
43	0.75
94	0.15
111	0.27
120	0.13
144	0.42
186	0.15
255	0.30
258	0.18
276	0.13
296	0.35
1027	0.80
1048	0.80
1056	0.20
1072	0.16
1073	0.90
1074	0.90
1082	0.80
1084	0.90
1088	0.12

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Die Handling and Bonding Information

Handling: All semiconductor chips should be handled with care to avoid damage or contamination from perspiration, salts, and skin oils. The use of plastic tipped tweezers or vacuum pickup is strongly recommended for the handling and placing of individual components. Bulk handling should ensure that abrasion and mechanical shock are minimized.

Die Attach Surface: Die can be mounted with an 80Au/Sn20, eutectic solder preform, RoHS compliant solders or electrically conductive silver epoxy. The metal RF and D.C. ground plane mounting surface must be free of contamination and should have a surface flatness of < ± 0.002 ".

Eutectic Die Attachment Using Hot Gas Die Bonder: A work surface temperature of 255°C is recommended. When hot forming gas (95%N/5%H) is applied, the work area temperature should be approximately 290°C. The chip should not be exposed to temperatures greater than 320°C for more than 10 seconds.

Eutectic Die Attachment Using Reflow Oven: For recommended reflow profile refer to pages 5-7 of <u>Application Note 538</u> "Surface Mounting Instructions",

Electrically Conductive Epoxy Die Attachment: A controlled amount of electrically conductive, silver epoxy, approximately 1–2 mils in thickness, should be used to minimize ohmic and thermal resistance. A thin epoxy fillet should be visible around the perimeter of the chip after placement to ensure full area coverage. Cure conductive epoxy per manufacturer's schedule. Typically 150°C for 1 hour.

Wire and Ribbon Bonding: The die anode bond pads have a Ti-Pt-Au metallization scheme, with a final gold thickness of 1.0 micron. Thermo-compression or thermo-sonic wedge bonding of either gold wire or ribbon is recommended. A bonder heat stage temperature setting of 200°C, tool tip temperature of 150°C and a force of 18 to 50 grams is suggested. Ultrasonic energy may also be used but should be adjusted to the minimum amplitude required to achieve an acceptable bond. Excessive energy may cause the anode metallization to separate from the chip. Automatic ball or wedge bonding may also be used.

For more detailed handling and assembly instructions, see <u>Application Note M541</u>, "Bonding and Handling Procedures for Chip Diode Devices".

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